

BAT42 and **BAT43**

Small-Signal Diode Schottky Diodes

Features

- ◆ For general purpose applications.
 ◆ These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- ◆ This diode is also available in the MiniMELF case with type designation LL42 to LL43.

Mechanical Data

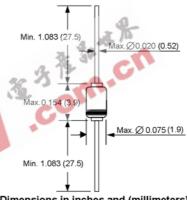
◆ Case: DO-35 Glass Case ◆ Weight: approx. 0.13g

Maximum Ratings and Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit	
Repetitive peak reverse voltage	V _{RRM}	30	Volts	
Forward continuous current at T _{amb} =25°C	ļ _F	200 (1)	mA	
Repetitive peak forward Current at tp<1s, δ <0.5, T_{amb} =25°C	I _{FRM}	500 (1)	mA	
Surge forward current at t_p <10ms, T_{amb} =25°C	I _{FSM}	4 (1)	Amps	
Power dissipation (1) at T _{amb} =65°C	P _{tot}	200 (1)	mW	
Thermal resistance junction to ambient air	$R_{_{\theta JA}}$	300 (1)	°C/W	
Junction temperature	T _j	125	°C	
Ambient operating temperature range	T _{amb}	-65 to +125	°C	
Storage temperature range	T _s	-65 to +150	°C	

DO-204AH (DO-35 Glass)



Dimensions in inches and (millimeters)



Electrical Characteristics

(1 ₃ =25°C unless otherwise noted.)									
Parameter		Symbol	Test Condition	Min.	Тур.	Max.	Unit		
Reverse breakdown voltage		V _{(BR)R}	I _R =100uA (pulsed)	30	-	-	Volts		
Leakage current pulse test t _o <300us, δ<2%		I _R	V _R =25V V _R =25V, T _i =100°C	-	-	0.5 100	uА		
Forward voltage pulse test t _p <300us, δ<2%	BAT42, 43 BAT42 BAT43 BAT43 BAT43	V _F	_=200mA _=10mA _=50mA _=2mA _=15mA	- - - 0.26	- - - -	1.0 0.40 0.65 0.33 0.45	Volt		
Capacitance		C _{tot}	V _R =1V, f=1MHz	-	7	-	pF		
Reverse recovery time		t _{rr}	$I_F=10\text{mA}, I_R=10\text{mA},$ $I_T=1\text{mA}, R_L=100\Omega$	-	-	5	nS		
Detection efficiency		η,	R_L =15K Ω , C_L =300pF f=45MHz, V_{RF} =2V	80	-	-	%		

1. Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.